



CHENMKO ENTERPRISE CO.,LTD

Lead free devices

**SURFACE MOUNT
NPN Switching Transistor**

VOLTAGE 40 Volts CURRENT 0.2 Ampere

CH3904ZPT

APPLICATION

- * Telephony and professional communication equipment.
- * Other switching applications.

FEATURE

- * Small flat package. (SC-73/SOT-223)
- * Low current (Max.=200mA).
- * Suitable for high packing density.
- * Low voltage (Max.=40V) .
- * High saturation current capability.
- * Voltage controlled small signal switch.

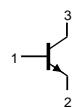
CONSTRUCTION

- * Two NPN transistors in one package.

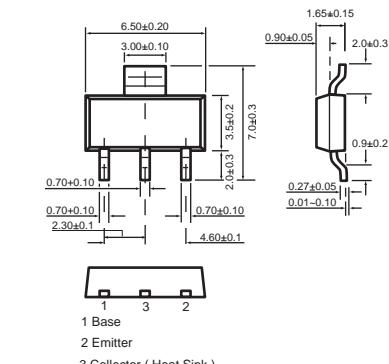
MARKING

* ZIN

CIRCUIT



SC-73/SOT-223



Dimensions in millimeters

SC-73/SOT-223

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	—	60	V
V_{CEO}	collector-emitter voltage	open base	—	40	V
V_{EBO}	emitter-base voltage	open collector	—	6	V
I_C	collector current DC		—	200	mA
I_{CM}	peak collector current		—	200	mA
I_{BM}	peak base current		—	100	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25^\circ\text{C}$; note 1	—	2.0	W
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		—	150	°C
T_{amb}	operating ambient temperature		-65	+150	°C

Note

2004-07

1. Transistor mounted on an FR4 printed-circuit board.

RATING CHARACTERISTIC CURVES (CH3904ZPT)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	625	K/W

Note

- Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

$T_{amb} = 25^\circ C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{CBO}	collector cut-off current	$I_E = 0; V_{CB} = 30 V$	—	50	nA
I_{EBO}	emitter cut-off current	$I_C = 0; V_{EB} = 6 V$	—	50	nA
h_{FE}	DC current gain	$V_{CE} = 1 V$; note 1 $I_C = 0.1 mA$ $I_C = 1 mA$ $I_C = 10 mA$ $I_C = 50 mA$ $I_C = 100 mA$	60 80 100 60 30	— — 300 — —	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 10 mA; I_B = 1 mA$	—	200	mV
		$I_C = 50 mA; I_B = 5 mA$	—	300	mV
V_{BEsat}	base-emitter saturation voltage	$I_C = 10 mA; I_B = 1 mA$	650	850	mV
		$I_C = 50 mA; I_B = 5 mA$	—	950	mV
C_c	collector capacitance	$I_E = i_e = 0; V_{CB} = 5 V; f = 1 MHz$	—	4	pF
C_e	emitter capacitance	$I_C = i_c = 0; V_{BE} = 500 mV; f = 1 MHz$	—	8	pF
f_T	transition frequency	$I_C = 10 mA; V_{CE} = 20 V; f = 100 MHz$	300	—	MHz
F	noise figure	$I_C = 100 \mu A; V_{CE} = 5 V; R_S = 1 k\Omega; f = 10 Hz to 15.7 kHz$	—	5	dB

Switching times (between 10% and 90% levels);

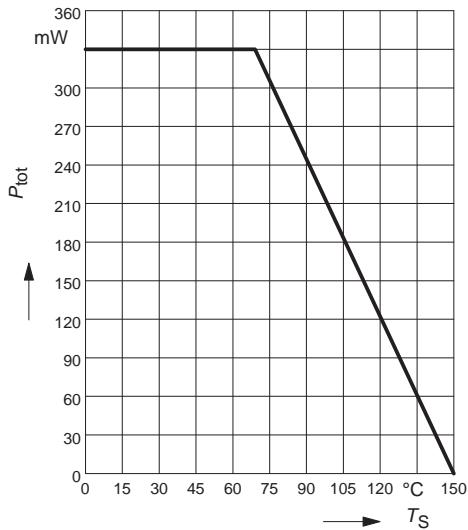
t_{on}	turn-on time	$I_{Con} = 10 mA; I_{Bon} = 1 mA; I_{Boff} = -1 mA$	—	65	ns
t_d	delay time		—	35	ns
t_r	rise time		—	35	ns
t_{off}	turn-off time		—	240	ns
t_s	storage time		—	200	ns
t_f	fall time		—	50	ns

Note

- Pulse test: $t_p \leq 300 \mu s; \delta \leq 0.02$.

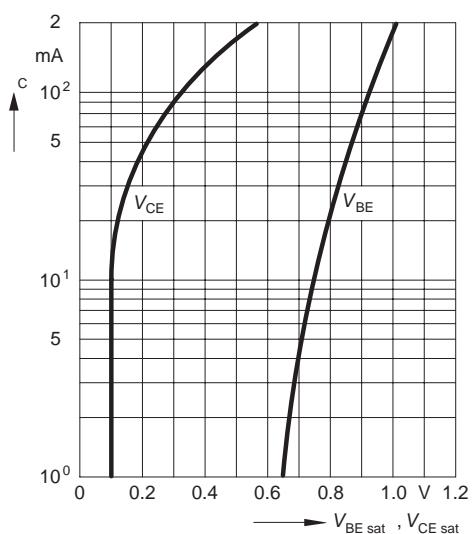
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Total power dissipation $P_{\text{tot}} = f(T_S)$



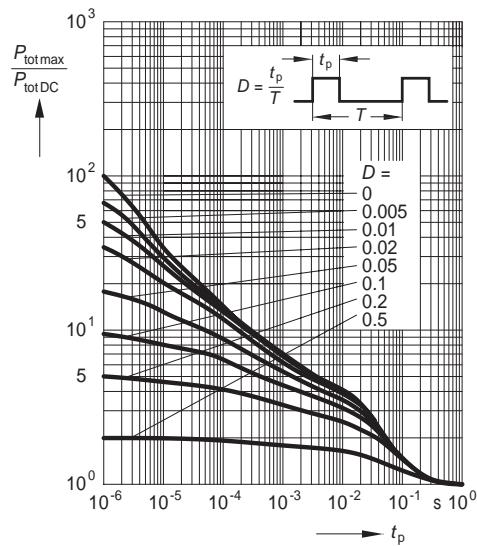
Saturation voltage $I_C = f(V_{BE\text{sat}}, V_{CE\text{sat}})$

$$h_{FE} = 10$$



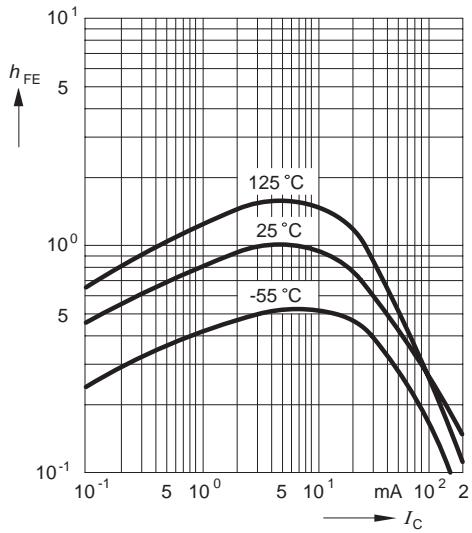
Permissible pulse load

$$P_{\text{totmax}} / P_{\text{totDC}} = f(t_p)$$



DC current gain $h_{FE} = f(I_C)$

$$V_{CE} = 10V, \text{ normalized}$$

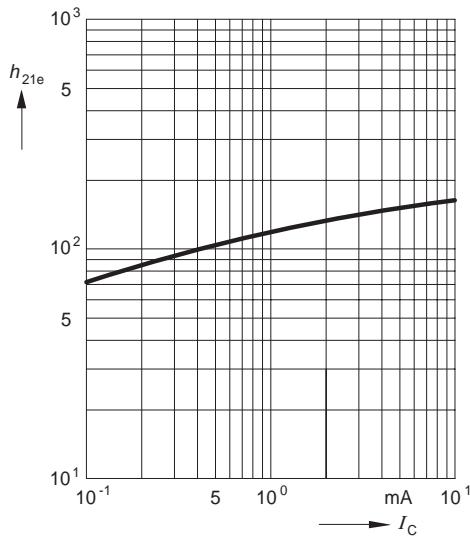


RATING CHARACTERISTIC CURVES (CH3904ZPT)

Short-circuit forward current

transfer ratio $h_{21e} = f(I_C)$

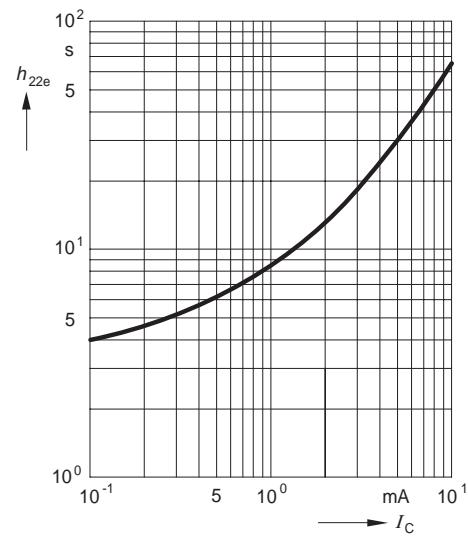
$V_{CE} = 10V, f = 1MHz$



Open-circuit output admittance

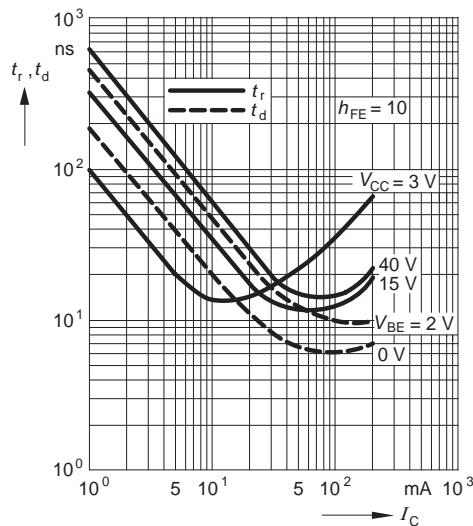
$h_{22e} = f(I_C)$

$V_{CE} = 10V, f = 1MHz$

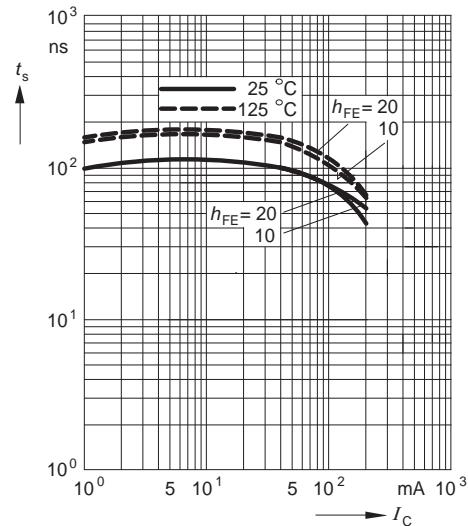


Delay time $t_d = f(I_C)$

Rise time $t_r = f(I_C)$

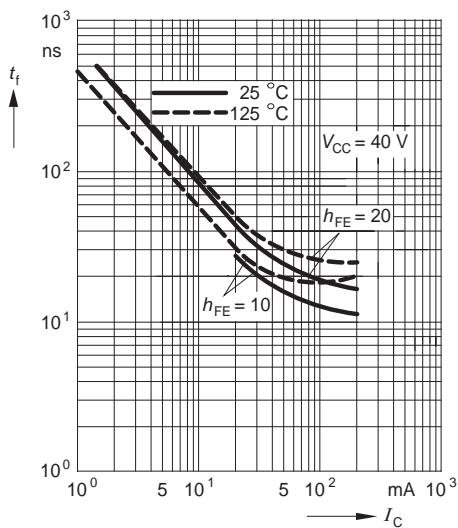


Storage time $t_{stg} = f(I_C)$

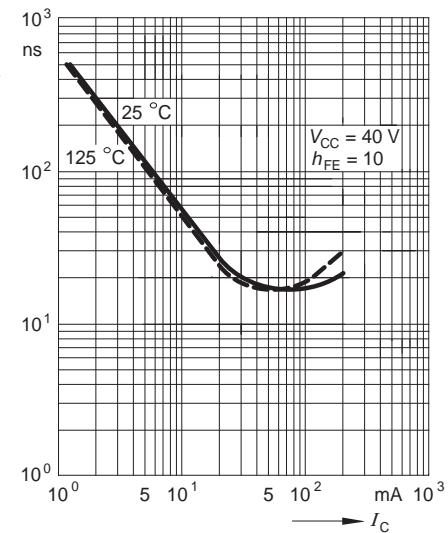


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Fall time $t_f = f(I_C)$



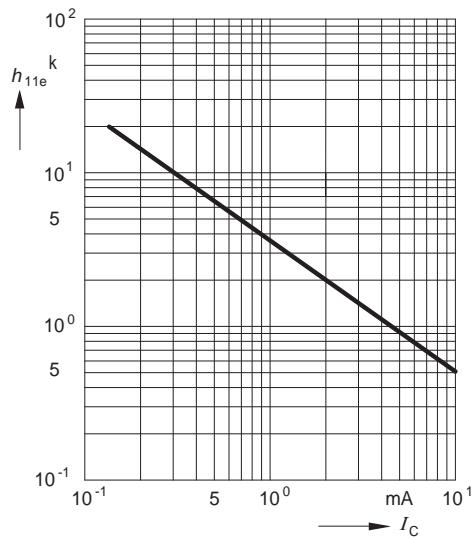
Rise time $t_r = f(I_C)$



Input impedance

$$h_{11e} = f(I_C)$$

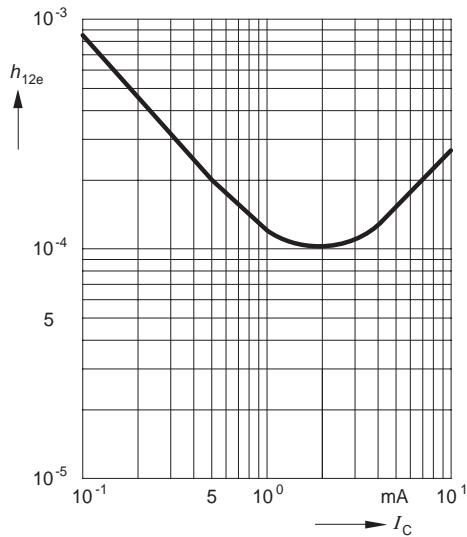
$V_{CE} = 10\text{V}$, $f = 1\text{kHz}$



Open-circuit reverse voltage

$$\text{transfer ratio } h_{12e} = f(I_C)$$

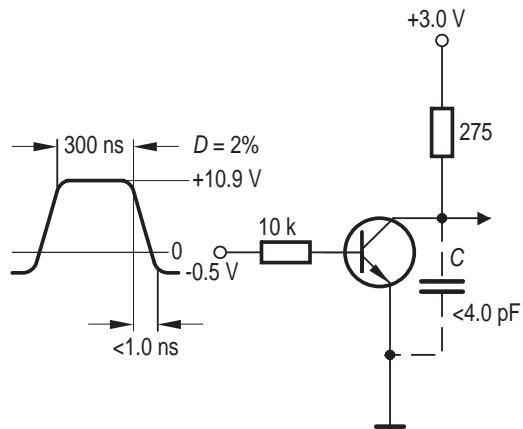
$V_{CE} = 10\text{V}$, $f = 1\text{kHz}$



RATING CHARACTERISTIC CURVES (CH3904ZPT)

Test circuits

Delay and rise time



Storage and fall time

